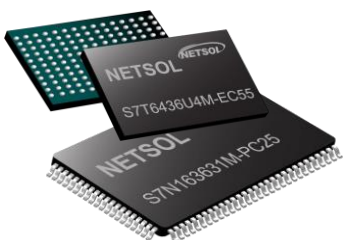




NETSOL Product List

- **Asynchronous Fast SRAM**
- **Asynchronous Low Power SRAM**
- **Synchronous SRAM**
- **DDR SRAM**
- **Quadruple SRAM**
- **MRAM**



High Quality & High Performance Memory Provider

1Q, 2017
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NETSOL SRAM Product List

◆ Asynchronous FAST SRAM

- Density and Organization : 1Mb, 2Mb, 4Mb, 8Mb, 16Mb, 32Mb, x8/x16 Org.
- Temperature : Commercial, Industrial, and Automotive Temperature (-40 °C to 125 °C) support
- POWER : 1.8V, 2.5V, 3.3V, 5.0V
- PKG Type : TSOP, FBGA, sTSOP, ...
- Application : Industrial equipment with High speed, Easy application, Long-term Support, Small footprint, Stable supplies

Density	Org.	Part Number	Vdd(V)	Access Time	Package	Availability
1M bit	64Kx16	S6R1016W1A	1.65~3.6	8/10/12/15ns	44TSOP2 48FBGA	Now
		S6R1016V1A	3.3	8/10ns		Now
		S6R1016C1A	5.0	10ns		Now
	128Kx8	S6R1008W1A	1.65~3.6	8/10/12/15ns	32sTSOP1 36FBGA	Now
		S6R1008V1A	3.3	8/10ns		Now
		S6R1008C1A	5.0	10ns		Now
2M bit	128Kx16	S6R2016W1A	1.65~3.6	8/10/12/15ns	44TSOP2 48FBGA	Now
		S6R2016V1A	3.3	8/10ns		Now
		S6R2016C1A	5.0	10ns		Now
	256Kx8	S6R2008W1A	1.65~3.6	8/10/12/15ns	44TSOP2 36FBGA	Now
		S6R2008V1A	3.3	8/10ns		Now
		S6R2008C1A	5.0	10ns		Now
4M bit	256Kx16	S6R4016W1A	1.65~3.6	8/10/12/15ns	44TSOP2 48FBGA	Now
		S6R4016V1A	3.3	8/10ns		Now
		S6R4016C1A	5.0	10ns		Now
	512Kx8	S6R4008W1A	1.65~3.6	8/10/12/15ns	44TSOP2 36FBGA	Now
		S6R4008V1A	3.3	8/10ns		Now
		S6R4008C1A	5.0	10ns		Now
8M bit	512Kx16	S6R8016W1A	1.65~3.6	8/10/12/15ns	44TSOP2 48FBGA	Now
		S6R8016C1A	5.0	10ns		Now
	1Mx8	S6R8008W1A	1.65~3.6	8/10/12/15ns	44TSOP2 48FBGA	Now
		S6R8008C1A	5.0	10ns		Now
16M bit	1Mx16	S6R1616W1M	1.65~3.6	8/10/12/15ns	48TSOP1 48FBGA	Now
		S6R1616V1M	3.3	8/10ns		Now
		S6R1616C1M	5.0	10ns		Now
	2Mx8	S6R1608W1M	1.65~3.6	8/10/12/15ns	44TSOP2 48FBGA	Now
		S6R1608V1M	3.3	8/10ns		Now
		S6R1608C1M	5.0	10ns		Now
32M bit	2Mx16	S6R3216W1M	1.65~3.6	8/10/12/15ns	48FBGA	Now
	4Mx8	S6R3208W1M	1.65~3.6	8/10/12/15ns		Now

Notes

1. All of packaged asynchronous fast products are based on RoHS6 or lead free.
2. Industrial temperature range is recommended, but commercial one is available

NETSOL SRAM Product List

◆ Asynchronous Low Power SRAM

- Density and Organization : 256Kb, 1Mb, 2Mb, 4Mb, 8Mb, x8/x16 Org.
- Temperature : Commercial, Industrial, and Automotive Temperature (-40 °C to 125 °C) support
- POWER : 1.8V, 2.5V, 3.3V, 5.0V
- PKG Type : TSOP, FBGA, sTSOP, SOP ...
- Application : Industrial equipment with Low power consumption, Mobile application, Easy application, Long-term Support, Small footprint, Stable supplies, IoT

Density	Org.	Part Number	Vdd(V)	C/S Option	Speed - tAA(ns)	Package	Availability
1M bit	64Kx16	S6L1016W1M	2.3~3.6	1 C/S	45/55/70ns	44TSOP2, 48FBGA	Now
		S6L1016C1M	4.5~5.5	1 C/S		44TSOP2, 48FBGA	Now
	128Kx8	S6L1008W2M	2.3~3.6	2 C/S	45/55/70ns	32sTSOP1, 2TSOP1, 32SOP	Now
		S6L1008C2M	4.5~5.5	2 C/S			Now
2M bit	128Kx16	S6L2016W1M	2.3~3.6	1 C/S	45/55/70ns	44TSOP2,48FBGA	Now
		S6L2016W2M	2.3~3.6	2 C/S		48FBGA	Now
		S6L2016C1M	4.5~5.5	1 C/S		44TSOP2	Now
	256Kx8	S6L2008W1M	2.3~3.6	1 C/S	45/55/70ns	36FBGA	Now
		S6L2008W2M	2.3~3.6	2 C/S		32sTSOP1, 32TSOP1, 32TSOP2, 32SOP	Now
		S6L2008C2M	4.5~5.5	2 C/S			Now
4M bit	256Kx16	S6L4016W1M	2.3~3.6	1 C/S	45/55/70ns	44TSOP2, 48FBGA	Now
		S6L4016W2M	2.3~3.6	2 C/S		44TSOP2, 48FBGA	Now
		S6L4016C1M	4.5~5.5	1 C/S		44TSOP2	Now
		S6L4016C2M	4.5~5.5	2 C/S		44TSOP2	Now
	512Kx8	S6L4008W1M	2.3~3.6	1 C/S	45/55/70ns	32sTSOP1, 32TSOP1, 32TSOP2, 32SOP	Now
		S6L4008C1M	4.5~5.5	1 C/S			Now
8M bit	512Kx16	S6L8016W1M	2.3~3.6	1 C/S	45/55/70ns	44TSOP2, 48FBGA	Now
		S6L8016W2M	2.3~3.6	2 C/S		44TSOP2, 48FBGA	Now
		S6L8016C1M	4.5~5.5	1 C/S		44TSOP2, 48FBGA	Now
		S6L8016C2M	4.5~5.5	2 C/S		48FBGA	Now
	1Mx8	S6L8008W2M	2.3~3.6	2 C/S	45/55/70ns	44TSOP2, 48FBGA	Now
		S6L8008C2M	4.5~5.5	2 C/S		44TSOP2, 48FBGA	Now
16M bit	1Mx16	S6L1616W1M	2.3~3.6	1 C/S	45/55/70ns	48TSOP1, 48FBGA	Under Consideration
		S6L1616W2M	2.3~3.6	2 C/S		48TSOP1, 48FBGA	
	2Mx8	S6L1608W1M	2.3~3.6	1 C/S	45/55/70ns	44TSOP2, 48FBGA	
		S6L1608W2M	2.3~3.6	2 C/S		44TSOP2, 48FBGA	
32M bit	2Mx16	S6L3216W1M	2.3~3.6	1 C/S	45/55/70ns	48FBGA	Under Consideration
		S6L3216W2M	2.3~3.6	2 C/S		48FBGA	
	4Mx8	S6L3208W1M	2.3~3.6	1 C/S	45/55/70ns	48FBGA	
		S6L3208W2M	2.3~3.6	2 C/S		48FBGA	

Notes

1. All of packaged asynchronous fast products are based on RoHS6 or lead free.
2. Industrial temperature range is recommended, but commercial one is available

NETSOL SRAM Product List

◆ Synchronous SRAM

- Density and Organization : 4Mb, 9Mb, 18Mb, 36Mb, 72Mb, x18/x36 Org.
- Temperature : Commercial, Industrial temperature support
- POWER : 2.5V, 3.3V
- PKG Type : TQFP, FBGA, ...
- Application : Industrial equipment with High speed, Network equipment, Instrument, Medical equipment, Easy application, Long-term Support, Stable supplies

(1) Synchronous Pipe Burst SRAM

Density	Org.	Part Number	Operating	VDD(V)	tCYC	Access Time	Package	Availability
4M bit	128Kx36	S7A403630M	SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
	256Kx18	S7A401830M	SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
9M bit	256Kx36	S7A803630M	SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
	512Kx18	S7A801830M	SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
18M bit	512Kx36	S7A163630M	SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
	1Mx18	S7A161830M	SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
36M bit	1Mx36	S7A323630M	SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
	2Mx18	S7A321830M	SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
72M bit	2Mx36	S7A643630M	SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
	4Mx18	S7A641830M	SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now

(2) Synchronous Flow Through SRAM

Density	Org.	Part Number	Operating	VDD(V)	tCYC	Access Time	Package	Availability
4M bit	128Kx36	S7B403635M	FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
	256Kx18	S7B401835M	FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
9M bit	256Kx36	S7B803635M	FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
	512Kx18	S7B801835M	FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
18M bit	512Kx36	S7B163635M	FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
	1Mx18	S7B161835M	FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
36M bit	1Mx36	S7B323635M	FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
	2Mx18	S7B321835M	FT	2.3~3.5	133MHz	6.5ns	100LQFP	Now
72M bit	2Mx36	S7B643635M	FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
	4Mx18	S7B641835M	FT	2.3~3.5	133MHz	6.5ns	100LQFP	Now

(3) NT Pipe Burst SRAM

Density	Org.	Part Number	Operating	VDD(V)	tCYC	Access Time	Package	Availability
4M bit	128Kx36	S7N403631M	NT_SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
	256Kx18	S7N401831M	NT_SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
9M bit	256Kx36	S7N803631M	NT_SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
	512Kx18	S7N801831M	NT_SPB	2.3~3.5	250MHz	2.6ns	100TQFP	Now
18M bit	512Kx36	S7N163631M	NT_SPB	2.3~3.5	250MHz	2.6ns	100TQFP 165FBGA	Now
	1Mx18	S7N161831M	NT_SPB	2.3~3.5	250MHz	2.6ns		Now
36M bit	1Mx36	S7N323631M	NT_SPB	2.3~3.5	250MHz	2.6ns	100TQFP 165FBGA	Now
	2Mx18	S7N321831M	NT_SPB	2.3~3.5	250MHz	2.6ns		Now

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72M bit	2Mx36	S7N643631M	NT_SPB	2.3~3.5	250MHz	2.6ns	100TQFP 165FBGA	Now
	4Mx18	S7N641831M	NT_SPB	2.3~3.5	250MHz	2.6ns		Now

(4) NT Flow Through SRAM

Density	Org.	Part Number	Operating	VDD(V)	tCYC	Access Time	Package	Availability
4M bit	128Kx36	S7M403635M	NT_FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
	256Kx18	S7M401835M	NT_FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
9M bit	256Kx36	S7M803635M	NT_FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
	512Kx18	S7M801835M	NT_FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
18M bit	512Kx36	S7M163635M	NT_FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
	1Mx18	S7M161835M	NT_FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
36M bit	1Mx36	S7M323635M	NT_FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
	2Mx18	S7M321835M	NT_FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
72M bit	2Mx36	S7M643635M	NT_FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now
	4Mx18	S7M641835M	NT_FT	2.3~3.5	133MHz	6.5ns	100TQFP	Now

Notes

- All of NTSRAM products are based on RoHS6.
All NTSRAM is based on 100TQFP including 165FBGA for NT-SPB.
- NTSRAM : Non-Turnaround Static Random Access Memory
- Both commercial temperature range and industrial are available.
- Single bin policy by 250Mhz for NT-SPB and by 6.5ns for NT-FT.
Faster than 250Mhz are possible upon request.
- Non-parity such as 32-bits is possible upon request.
- 1.8V Vdd is also available, please ask us.

◆ DDR SRAM

- Density and Organization : 18Mb, 36Mb, 72Mb, x18/x36 Org.
- Temperature : Commercial, Industrial temperature support
- POWER : 1.8V
- PKG Type : FBGA
- Application : Network equipment such as Look-up tables, Que Management, Policing and Packet buffers, Long-term Support, Stable supplies

Density	Org.	Part Number	Operating Mode	VDD(V)	Cycle time (MHz)	Burst Length	Clock Latency	Package	Availability
18M bit	512Kx36	S7I163682M	DDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	1Mx18	S7I161882M	DDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	512Kx36	S7K1636T2M	DDR II+	1.8	450,400,333	2	2	165FBGA	Now
	1Mx18	S7K1618T2M	DDR II+	1.8	450,400,333	2	2	165FBGA	Now
	512Kx36	S7K1636U2M	DDR II+	1.8	550,450,400	2	2.5	165FBGA	Now
	1Mx18	S7K1618U2M	DDR II+	1.8	550,450,400	2	2.5	165FBGA	Now
	512Kx36	S7L1636T2M	DDR II+, ODT	1.8	450,400,333	2	2	165FBGA	Now
	1Mx18	S7L1618T2M	DDR II+, ODT	1.8	450,400,333	2	2	165FBGA	Now
	512Kx36	S7L1636U2M	DDR II+, ODT	1.8	550,450,400	2	2.5	165FBGA	Now
	1Mx18	S7L1618U2M	DDR II+, ODT	1.8	550,450,400	2	2.5	165FBGA	Now

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	512Kx36	S7J163682M	DDR II, SIO	1.8	333,300,250	2	1.5	165FBGA	Now
	1Mx18	S7J161882M	DDR II, SIO	1.8	333,300,250	2	1.5	165FBGA	Now
	512Kx36	S7I163684M	DDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	1Mx18	S7I161884M	DDR II	1.8	333,300,250	4	1.5	165FBGA	Now
36M bit	2Mx18	S7I321882M	DDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	1Mx36	S7I323682M	DDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	1Mx36	S7K3236T2M	DDR II+	1.8	450,400,333	2	2	165FBGA	Now
	2Mx18	S7K3218T2M	DDR II+	1.8	450,400,333	2	2	165FBGA	Now
	1Mx36	S7K3236U2M	DDR II+	1.8	550,450,400	2	2.5	165FBGA	Now
	2Mx18	S7K3218U2M	DDR II+	1.8	550,450,400	2	2.5	165FBGA	Now
	1Mx36	S7L3236T2M	DDR II+, ODT	1.8	450,400,333	2	2	165FBGA	Now
	2Mx18	S7L3218T2M	DDR II+, ODT	1.8	450,400,333	2	2	165FBGA	Now
	1Mx36	S7L3236U2M	DDR II+, ODT	1.8	550,450,400	2	2.5	165FBGA	Now
	2Mx18	S7L3218U2M	DDR II+, ODT	1.8	550,450,400	2	2.5	165FBGA	Now
	1Mx36	S7I323684M	DDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	2Mx18	S7I321884M	DDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	1Mx36	S7J323682M	DDR II, SIO	1.8	333,300,250	2	1.5	165FBGA	Now
	2Mx18	S7J321882M	DDR II, SIO	1.8	333,300,250	2	1.5	165FBGA	Now
72M bit	2Mx36	S7I643682M	DDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	4Mx18	S7I641882M	DDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	2Mx36	S7K6436T2M	DDR II+	1.8	450,400,333	2	2	165FBGA	Now
	4Mx18	S7K6418T2M	DDR II+	1.8	450,400,333	2	2	165FBGA	Now
	2Mx36	S7K6436U2M	DDR II+	1.8	550,450,400	2	2.5	165FBGA	Now
	4Mx18	S7K6418U2M	DDR II+	1.8	550,450,400	2	2.5	165FBGA	Now
	2Mx36	S7L6436T2M	DDR II+, ODT	1.8	450,400,333	2	2	165FBGA	Now
	4Mx18	S7L6418T2M	DDR II+, ODT	1.8	450,400,333	2	2	165FBGA	Now
	2Mx36	S7L6436U2M	DDR II+, ODT	1.8	550,450,400	2	2.5	165FBGA	Now
	4Mx18	S7L6418U2M	DDR II+, ODT	1.8	550,450,400	2	2.5	165FBGA	Now
	2Mx36	S7J643682M	DDR II, SIO	1.8	333,300,250	2	1.5	165FBGA	Now
	4Mx18	S7J641882M	DDR II, SIO	1.8	333,300,250	2	1.5	165FBGA	Now
	2Mx36	S7I643684M	DDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	4Mx18	S7I641884M	DDR II	1.8	333,300,250	4	1.5	165FBGA	Now

Notes

1. All of DDR SRAM products are based on RoHS6.
2. All of RoHS5 or leaded type is recommended to convert it into RoHS6 or lead free.
3. Both commercial temperature range and industrial are available.
4. Lower bins such as 200Mhz and 167Mhz are recommended to 250Mhz.

NETSOL SRAM Product List

◆ Quadruple SRAM

- Density and Organization : 18Mb, 36Mb, 72Mb, 144Mb x18/x36 Org.
- Temperature : Commercial, Industrial temperature support
- POWER : 1.8V, (QDR I : 1.8V, 2.5V)
- PKG Type : FBGA
- Application : Network equipment such as Look-up tables, Que Management, Policing and Packet buffers, Long-term Support, Stable supplies

Density	Org.	Part Number	Operating Mode	VDD(V)	Cycle time (MHz)	Burst Length	Clock Latency	Package	Availability
18M bit	512Kx36	S7Q163662M	QDR I	1.8~2.5	167	2	1	165FBGA	Now
	1Mx18	S7Q161862M	QDR I	1.8~2.5	167	2	1	165FBGA	Now
	512Kx36	S7R163682M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	1Mx18	S7R161882M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	2Mx9	S7R160982M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	512Kx36	S7Q163664M	QDR I	1.8~2.5	167	4	1	165FBGA	Now
	1Mx18	S7Q161864M	QDR I	1.8~2.5	167	4	1	165FBGA	Now
	512Kx36	S7R163684M	QDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	1Mx18	S7R161884M	QDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	512Kx36	S7S1636T4M	QDR II+	1.8	450,400,333	4	2	165FBGA	Now
	1Mx18	S7S1618T4M	QDR II+	1.8	450,400,333	4	2	165FBGA	Now
	512Kx36	S7S1636U4M	QDR II+	1.8	550,450,400	4	2.5	165FBGA	Now
	1Mx18	S7S1618U4M	QDR II+	1.8	550,450,400	4	2.5	165FBGA	Now
	512Kx36	S7T1636T4M	QDR II+, ODT	1.8	450,400,333	4	2	165FBGA	Now
	1Mx18	S7T1618T4M	QDR II+, ODT	1.8	450,400,333	4	2	165FBGA	Now
	512Kx36	S7T1636U4M	QDR II+, ODT	1.8	550,450,400	4	2.5	165FBGA	Now
1Mx18	S7T1618U4M	QDR II+, ODT	1.8	550,450,400	4	2.5	165FBGA	Now	
36M bit	1Mx36	S7R323682M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	2Mx18	S7R321882M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	4Mx9	S7R320982M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	1Mx36	S7S3236U2M	QDR II+	1.8	450,400,366	2	2.5	165FBGA	Now
	2Mx18	S7S3218U2M	QDR II+	1.8	450,400,366	2	2.5	165FBGA	Now
	1Mx36	S7R323684M	QDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	2Mx18	S7R321884M	QDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	4Mx9	S7R320984M	QDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	1Mx36	S7S3236T4M	QDR II+	1.8	450,400,333	4	2	165FBGA	Now
	2Mx18	S7S3218T4M	QDR II+	1.8	450,400,333	4	2	165FBGA	Now
	1Mx36	S7S3236U4M	QDR II+	1.8	550,450,400	4	2.5	165FBGA	Now
	2Mx18	S7S3218U4M	QDR II+	1.8	550,450,400	4	2.5	165FBGA	Now
	1Mx36	S7T3236T4M	QDR II+, ODT	1.8	450,400,333	4	2	165FBGA	Now
	2Mx18	S7T3218T4M	QDR II+, ODT	1.8	450,400,333	4	2	165FBGA	Now
	1Mx36	S7T3236U4M	QDR II+, ODT	1.8	550,450,400	4	2.5	165FBGA	Now
	2Mx18	S7T3218U4M	QDR II+, ODT	1.8	550,450,400	4	2.5	165FBGA	Now
72M bit	2Mx36	S7R643682M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	4Mx18	S7R641882M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	8Mx9	S7R640982M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now

NETSOL SRAM Product List

	2Mx36	S7S6436U2M	QDR II+	1.8	450,400,366	2	2.5	165FBGA	Now
	4Mx18	S7S6418U2M	QDR II+	1.8	450,400,366	2	2.5	165FBGA	Now
	2Mx36	S7T6436T2M	QDR II+, ODT	1.8	400,357,333	2	2	165FBGA	Now
	4Mx18	S7T6418T2M	QDR II+, ODT	1.8	400,357,333	2	2	165FBGA	Now
	2Mx36	S7R643684M	QDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	4Mx18	S7R641884M	QDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	2Mx36	S7S6436T4M	QDR II+	1.8	450,400,333	4	2	165FBGA	Now
	4Mx18	S7S6418T4M	QDR II+	1.8	450,400,333	4	2	165FBGA	Now
	2Mx36	S7S6436U4M	QDR II+	1.8	550,450,400	4	2.5	165FBGA	Now
	4Mx18	S7S6418U4M	QDR II+	1.8	550,450,400	4	2.5	165FBGA	Now
	2Mx36	S7T6436T4M	QDR II+, ODT	1.8	450,400,333	4	2	165FBGA	Now
	4Mx18	S7T6418T4M	QDR II+, ODT	1.8	450,400,333	4	2	165FBGA	Now
	2Mx36	S7T6436U4M	QDR II+, ODT	1.8	550,450,400	4	2.5	165FBGA	Now
	4Mx18	S7T6418U4M	QDR II+, ODT	1.8	550,450,400	4	2.5	165FBGA	Now
144M bit	4Mx36	S7R443682M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	8Mx18	S7R441882M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	16Mx9	S7R440982M	QDR II	1.8	333,300,250	2	1.5	165FBGA	Now
	4Mx36	S7S4436U2M	QDR II+	1.8	450,400,366	2	2.5	165FBGA	Now
	8Mx18	S7S4418U2M	QDR II+	1.8	450,400,366	2	2.5	165FBGA	Now
	4Mx36	S7T4436T2M	QDR II+, ODT	1.8	400,357,333	2	2	165FBGA	Now
	8Mx18	S7T4418T2M	QDR II+, ODT	1.8	400,357,333	2	2	165FBGA	Now
	4Mx36	S7R443684M	QDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	8Mx18	S7R441884M	QDR II	1.8	333,300,250	4	1.5	165FBGA	Now
	4Mx36	S7S4436T4M	QDR II+	1.8	450,400,333	4	2	165FBGA	Now
	8Mx18	S7S4418T4M	QDR II+	1.8	450,400,333	4	2	165FBGA	Now
	4Mx36	S7S4436U4M	QDR II+	1.8	550,450,400	4	2.5	165FBGA	Now
	8Mx18	S7S4418U4M	QDR II+	1.8	550,450,400	4	2.5	165FBGA	Now
	4Mx36	S7T4436T4M	QDR II+, ODT	1.8	450,400,333	4	2	165FBGA	Now
	8Mx18	S7T4418T4M	QDR II+, ODT	1.8	450,400,333	4	2	165FBGA	Now
	4Mx36	S7T4436U4M	QDR II+, ODT	1.8	550,450,400	4	2.5	165FBGA	Now
8Mx18	S7T4418U4M	QDR II+, ODT	1.8	550,450,400	4	2.5	165FBGA	Now	

Notes

1. All of Quadruple SRAM products are based on RoHS6.
2. All of RoHS5 or leaded type is recommended to convert it into RoHS6 or lead free.
3. Both commercial temperature range and industrial are available.
4. Lower bins such as 200Mhz and 167Mhz are recommended to 250Mhz.

NETSOL MRAM Product List

◆ MRAM (Non-Volatile SRAM)

- Density and Organization : 128Kb, 256Kb, 1Mb, 4Mb, 16Mb x8/x16 Org.
- Temperature : Commercial, Industrial temperature support
- POWER : 2.7V, 3.3V
- PKG Type : 44TSOP2, 48FBGA, 8DFN, 16SOIC, 24FBGA
- Application : Network equipment, Enterprise RAID, Smart Meter, IoT, Industrial Equipment

Density	Org.	Part Number	VDD(V)	I/O Type	Speed (MHz)	Package	Availability
256K bit	32Kx8	S3R0808V1A	2.7V,3.3V	Parallel	35	44TSOP2, 48FBGA	Now
1M bit	64Kx16	S3R1016V1A	3.3V	Parallel	35	44TSOP2, 48FBGA	Now
	128Kx8	S3R1008V1A	2.7V,3.3V	Parallel	35	44TSOP2, 48FBGA	Now
4M bit	256Kx16	S3R4016V1A	3.3V	Parallel	35	44TSOP2, 48FBGA	Now
	512Kx8	S3R4008V1A	3.3V	Parallel	35	44TSOP2, 48FBGA	Now
16M bit	1Mx16	S3R1616V1B	3.3V	Parallel	35	54TSOP2, 48FBGA	Now
	2Mx8	S3R1608V1B	3.3V	Parallel	35	44TSOP2, 48FBGA	Now
128K bit	16Kx8	S3C0708V00A	3.3V	Serial	40	8DFN (Small Flag)	Now
256K bit	32Kx8	S3C0808V00A	3.3V	Serial	40	8DFN (Small Flag)	Now
1M bit	128Kx8	S3C1008V00M	3.3V	Serial	40	8DFN (Small Flag)	Now
4M bit	512Kx8	S3C4008V00M	3.3V	Serial	40,50	8DFN (Small Flag)	Now
1M bit	128Kx8	S3E1008Y00M	3.3V	Quad SPI	104	16SOIC, 24FBGA	Now

Notes

1. All of packaged asynchronous fast products are based on RoHS6 or lead free.
2. Industrial temperature range is recommended, but commercial one is available

Asynchronous SRAM Packaged Product Code Information



NETSOL
Memory

Async. SRAM : 6

Functional Mode
Fast SRAM : R,
Low Power SRAM : L

Density
64Kb : 06, 128Kb: 07
256Kb : 08, 512Kb: 09
1Mb : 10, 2Mb: 20
4Mb : 40, 8Mb: 80
16Mb: 16, 32Mb: 32

Organization
X4 : 04, X8: 08
X16: 16, X32: 32

VCC
5.0V: C, 3.3V: V, 1.8V~3.3V: W

Mode
CS Control 1pc : 1, CS Control 2pcs: 2

Generation
1st Generation: M, 2nd Generation: A, 3rd Generation: B

Special code
for customer
demand
(Default) : 00

Packing Type
Tray: 0, T&R: T

Speed
8ns: 08, 10ns: 10, 12ns: 12
15ns: 15, 20ns: 20, 35ns: 35
45ns: 45, 50ns: 50, 55ns: 55
70ns: 70, 85ns: 85

Temperature & Power
Commercial: C, Commercial L/P: L
Industrial: I, Industrial L/P: P
Automotive: A, Automotive L/P: Q

Package
44 TSOP2: U, 48 TSOP1: Y
32 sTSOP1: L, 48 FBGA: X
28/32 TSOP1: T, 32 TSOP2: N
32 SOP: B, 28 SOP: G

*** Note**

(1) ~ (14) : customer ordering code, appears on top of PKG
(16) ~ (18) : code for Labeling, appears on label on Box

Asynchronous SRAM Wafer/Dice Code Information



NETSOL
Memory

Async. SRAM : 6

Functional Mode
Fast SRAM : R,
Low Power SRAM : L

Density
64Kb : 06, 128Kb: 07
256Kb : 08, 512Kb: 09
1Mb : 10, 2Mb: 20
4Mb : 40, 8Mb: 80
16Mb: 16. 32Mb: 32

VCC
5.0V: C, 3.3V: V, 1.8V~3.3V: W

Mode
CS Control 1pc : 1, CS Control 2pcs: 2

Generation
1st Generation: M, 2nd Generation: A, 3rd Generation: B

Special code for
customer demand
(Default) : 00

Carrier Type
Cassette Type: 0,
Jar Type: 1

Test Level
Hot Temp, DC Sort: 1
Hot Temp, DC& AC Sort: 2
Hot & Cold Temp, DC& AC Sort: 3

Production Form
Wafer: W
Chip: C

** Note*

(1) ~ (11) : customer ordering code, appears on top of PKG

(12) ~ (14) : code for Labeling, appears on label on Box

Synchronous SRAM Code Information



NETSOL
Memory

Sync. SRAM : 7

Functional Mode
Refer below #1

Density
4Mb : 40, 8~9Mb: 80
16~18Mb : 16, 32~36Mb: 32
64~72Mb: 64, 144Mb: 44

Organization
X4 : 04, X8: 08, X9: 09
X16: 16, X32: 32, X36: 36

Vcc, Interface Mode
Refer below #2

Special code
for customer
demand
(Default) : 00

Packing Type
Tray: 0, T&R: T

Speed
Refer below #3

Temperature & Power
Commercial (0~70°C): C
Industrial (-40~85°C): I
Automotive (-40~125°C): A

Package
Lead Free QFP: P
Lead Free FBGA: E

Generation
1st Generation: M, 2nd Generation: A, 3rd Generation: B

#1 : Functional Mode

3 : Functional Mode				
Standard Sync.	Pipe Burst	Flow Through		
Synchronous	A	B		
NTSRAM	N	M		
Q/DDR	I	II	II+	II+/ODT
Quadruple	Q	R	S	T
DDR Com. I/O	D	I	K	L
DDR Sep. I/O		J		

#2 : Vcc, Interface Mode

Vcc, Interface Mode	Standard	Burst 2	Burst 4
2.5V/3.3V Wide, LVTTTL, 2E1D	30		
2.5V/3.3V Wide, LVTTTL, 2E2D	31		
2.5V/3.3V Wide, LVTTTL, SB-FT	35		
2.5V HSTL, 1.0 CLK Latency		62	64
1.8V HSTL, 1.5 CLK Latency		82	84
1.8V HSTL, 2.0 CLK Latency		T2	T4
1.8V HSTL, 2.5 CLK Latency		U2	U4

#3 : Speed

Speed	Code	Speed	Code
133MHz	13	450MHz	45
166MHz	16	500MHz	50
200MHz	20	550MHz	55
250MHz	25	600MHz	60
300MHz	30	650MHz	65
333MHz	33	666MHz	66
400MHz	40	800MHz	80
Speed	Code	Speed	Code
6.0ns	60	8.0ns	80
6.5ns	65	9.0ns	90
7.0ns	70	10.0ns	10
7.5ns	75	12ns	12

* Note

(1) ~ (14) : customer ordering code, appears on top of PKG

(16) ~ (18) : code for Labeling, appears on label on Box

MRAM Code Information



NETSOL
Memory

MRAM : 3

Functional Mode

Parallel : R
SSPI : C
DSPI : D
QSPI : E

Density

64Kb : 06, 128Kb: 07
256Kb : 08, 512Kb: 09
1Mb : 10, 2Mb: 20
4Mb : 40, 8Mb: 80
16Mb : 16, 32Mb: 32

Organization

x8 : 08, x16 : 16

VCC

3.3V: V, 3.0V: U, 2.5V : S, 2.5V~3.3V: W

VCC/VCCQ

3.3V/1.8V : Y 2.7V~3.6V/1.8V : X

Mode

Default : 0, CS Low Active : 1

Generation

1st Generation: M, 2nd Generation: A, 3rd Generation: B

Special code
for customer
demand
(Default) : 00

Packing Type

Tray: 0, T&R: T

Speed

20Mhz : 20, 33Mhz : 33
40Mhz : 40, 50mMhz : 50
104Mhz : 1A

Temperature & Power

Commercial: C

Industrial: I

Automotive: A

Package

8-DFN : C,

8-DFN Small Flag : K

16 SOP : S

24 FBGA : H

44 TSOP2: U,

48 TSOP1: Y

32 sTSOP1: L,

48 FBGA: X

* Note

(1) ~ (14) : customer ordering code, appears on top of PKG

(16) ~ (18) : code for Labeling, appears on label on Box

The background is a gradient of blue, transitioning from a darker shade at the top to a lighter shade at the bottom. On the right side, there is a pattern of small, light blue circles that appear to be part of a larger, curved structure. The text "Thank You!" is centered in the middle of the image.

Thank You!